

Can a solar cell co-assemble a self-assembled molecule at the buried interface?

Here we report a molecular hybrid at the buried interface in inverted perovskite solar cells that co-assembled the popular self-assembled molecule [4-(3,6-dimethyl-9H-carbazol-9-yl)butyl]phosphonic acid (Me-4PACz) with the multiple aromatic carboxylic acid 4,4',4''-nitrotribenzoic acid (NTBA) to improve the heterojunction interface.

Why is buried-interface engineering important for perovskite solar cells?

Buried-interface engineering is crucial to the performance of perovskite solar cells. Self-assembled monolayers and buffer layers at the buried interface can optimize charge transfer and reduce recombination losses. However, the complex mechanisms and the difficulty in selecting suitable functional groups pose great challenges.

Do deep-level defects limit the efficiency of $\text{Sb}_2(\text{S}, \text{Se})_3$ solar cells?

However, a multitude of deep-level defects significantly limit the efficiency of $\text{Sb}_2(\text{S}, \text{Se})_3$ solar cells. In this study, the density of the surface and deep-level defects was reduced by adding a monoatomic Al_2O_3 layer on the surface of CdS film.

What causes buried-interface degradation in Sn-Pb perovskite solar cells?

Combining theoretical and experimental approaches, we elucidate that deprotonation of the acidic hole-transport layer (HTL) is the root cause of buried-interface degradation in Sn-Pb perovskite solar cells under operation.

Can antimony selenosulfide be used in photovoltaic technology?

Antimony selenosulfide ($\text{Sb}_2(\text{S}, \text{Se})_3$) reveals excellent optoelectronic characteristics, positioning it as a propitious light-absorbing substance with potential applications in photovoltaic technology. However, a multitude of deep-level defects significantly limit the efficiency of $\text{Sb}_2(\text{S}, \text{Se})_3$ solar cells.

How to achieve high efficiency of $\text{Sb}_2(\text{S} \& \text{SE})_3$ solar cells?

Surprisingly, high efficiency of 9.39% $\text{Sb}_2(\text{S}, \text{Se})_3$ solar cells has been obtained with the addition of monoatomic Al_2O_3 layer based on the adjustment crystal orientation, tailored energy band structure and reduced density of deep-level defects.

Effective surface treatment for efficient and stable inverted inorganic CsPbI_2Br perovskite solar cells. ... The interest in all-inorganic perovskite solar cells (PSCs) featuring a p-i-n structure is on the rise, attributed to their superior heat resistance and adaptability with tandem cell methods. ... Passivation of the buried interface via ...

Despite perovskite solar cells (PSCs) based on a SnO_2 hole-blocking layer (HBL) are achieving excellent performance, the non-perfect buried interface between the SnO_2 HBL and the perovskite layer is still an

obstacle in achieving further improvement in power conversion efficiency (PCE) and stability. The poor morphology with numerous defects and the ...

Inverted perovskite solar cells (IPSCs) are a promising technology for commercialization due to their reliable operation and scalable fabrication. ... some interface issue can trigger IPSCs to become unstable, such as the voids in the buried interface [9], [10], the separation of self-assembled ... the PSCs with BNT treatment exhibited a steady ...

The impact of performance-enhancing NaF/RbF postdeposition treatments on the deeply buried Cu(In,Ga)Se₂/Mo thin-film solar cell interface is studied by making it accessibly by stripping off ...

Combining theoretical and experimental approaches, we elucidate that deprotonation of the acidic hole-transport layer (HTL) is the root cause of buried-interface ...

The planar- or submicrometric-textured front-side Si wafer not only requires additional etching treatments but also experiences additional optical loss due to the absence of ...

4 ???· Carrier transport and recombination at the buried interface of perovskite have seriously restricted the further development of inverted perovskite solar cells (PSCs). Herein, an ...

Meticulous engineering of the buried interface between the TiO₂ electron-transport layer and the CsPbI_{3-x}Br_x perovskite is crucial for interfacial charge transport and perovskite crystallization, thereby minimizing energy losses and achieving highly efficient and stable inorganic perovskite solar cells (PSCs). Herein, a functional molecular bridge is ...

The device with the passivation of PEABr at the buried interface illustrates better PV performance than that with only DMF washing or without PEABr passivation, and the DMF washing on the MeO-2PACz/Al₂O₃ film reduces the J_{SC}. Thus, the treatment of PEABr at the buried interface has a positive effect on the performance of PSCs, rather than DMF.

CsPbI₂Br perovskite is known for its advantages over its organic-inorganic hybrid counterpart including better thermal stability and appropriate bandgap for the front sub-cell of tandem solar ...

Large open-circuit voltage (V_{oc}) loss is the main issue limiting the efficiency improvement in wide bandgap perovskite solar cells (PerSCs). Herein, a facile buried interface treatment by ...

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